AUTOMOTIVE GRADE

COMPLIANT

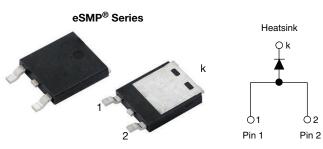
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# Vishay Semiconductors

# Hyperfast Rectifier, 6 A FRED Pt®



SlimDPAK (TO-252AE)

#### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	6 A			
$V_R$	600 V			
V <sub>F</sub> at I <sub>F</sub>	1.26 V			
t <sub>rr</sub> (typ.)	16 ns			
T <sub>J</sub> max.	175 °C			
Package	SlimDPAK (TO-252AE)			
Circuit configuration	Single			

### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub> and soft recovery
- For PFC CRM / CCM operation
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
  - Automotive ordering code: base P/NHM3, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

### **TYPICAL APPLICATIONS**

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters, or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

### **MECHANICAL DATA**

Case: SlimDPAK (TO-252AE)

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per

J-STD-002

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 148 °C	6	۸		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_J = 25$ °C, 10 ms sine pulse wave	70	A		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C		

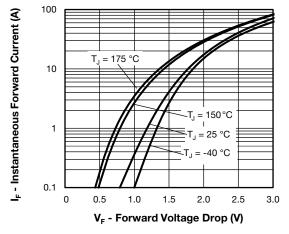
<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-		
Forward voltage V <sub>F</sub>	V	I <sub>F</sub> = 6 A	-	1.6	2.10	V	
	I <sub>F</sub> = 6 A, T <sub>J</sub> = 150 °C	-	1.26	1.70			
Reverse leakage current		$V_R = V_R$ rated	-	-	5		
	I <sub>R</sub>	T <sub>J</sub> = 150 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	250	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	10	-	pF	

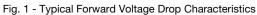
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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
		$I_F = 1 A, dI_F/dt = 50$	0 A/μs, V <sub>R</sub> = 30 V	-	22	-	
	t <sub>rr</sub>	$I_F = 1 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	16	-	ns
Reverse recovery time		$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{RR} = 0.25 \text{ A}$		-	-	28	
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 6 A dI <sub>F</sub> /dt = 500 A/μs V <sub>R</sub> = 400 V	-	28	-	-
		T <sub>J</sub> = 125 °C		-	60	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	5.5	-	Α
		T <sub>J</sub> = 125 °C		-	8.5	-	_ ^
Deverge vecesies, charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	100	-	nC
Reverse recovery charge		T <sub>J</sub> = 125 °C		-	250	-	110

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to mount	$R_{thJM}$		-	-	2.5	°C/W
Weight			-	0.20	-	g
Marking device		Case style SlimDPAK (TO-252AE)	6EVH06			





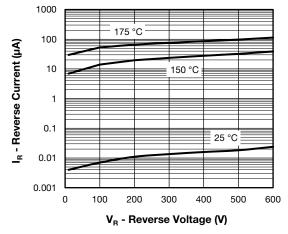


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

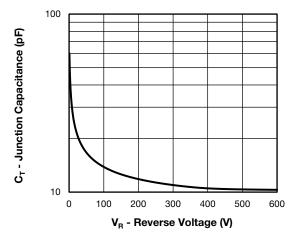


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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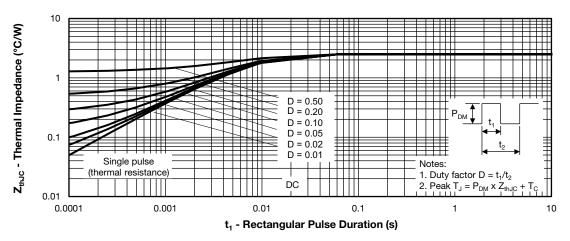


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

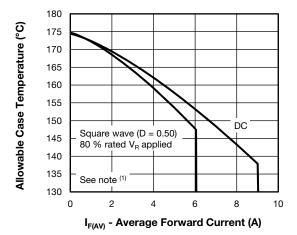


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

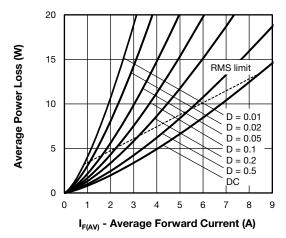


Fig. 6 - Forward Power Loss Characteristics

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$ 

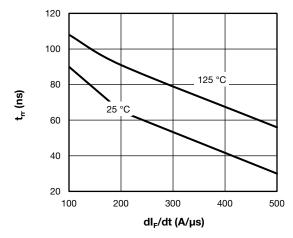


Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

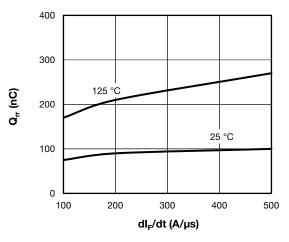
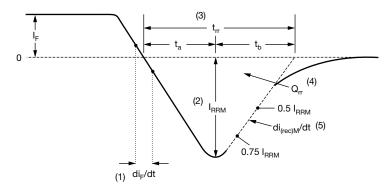


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

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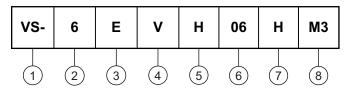


- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_{r}$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{rr}$  area under curve defined by  $\mathbf{t}_{rr}$  and  $\mathbf{I}_{RRM}$ 
  - $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$
- (5)  $di_{(rec)M}/dt$  peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 9 - Reverse Recovery Waveform and Definitions

### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Current rating (6 = 6 A)
- 3 Circuit configuration:

E = single die

- 4 V = SlimDPAK
- Frocess type:

  H = hyperfast recovery
- =
- 6 Voltage code (06 = 600 V)
- T H = AEC-Q101 qualified
- 8 Environmental digit:

M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-6EVH06HM3/I	0.20	I	4500	13"diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?96081</u>					
Part marking information	www.vishay.com/doc?96085				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96868				

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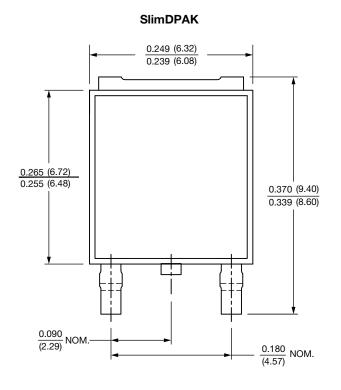


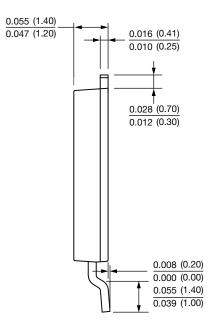


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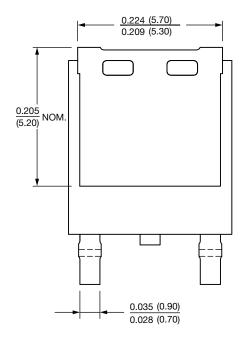
# **SlimDPAK**

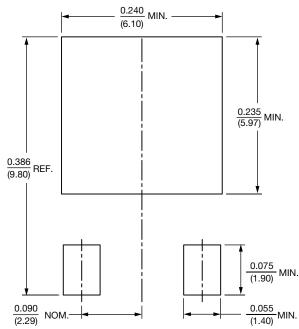
### **DIMENSIONS** in inches (millimeters)





### **Mounting Pad Layout**





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